



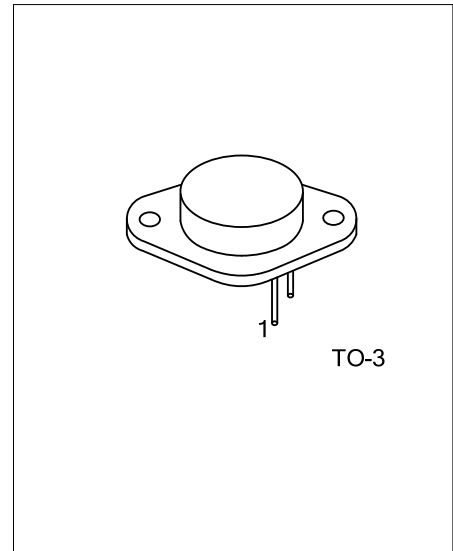
2N3055

NPN SILICON TRANSISTOR

SILICON NPN TRANSISTORS

DESCRIPTION

The UTC 2N3055 is a silicon NPN transistor in TO-3 metal case. It is intended for power switching circuits, series and shunt regulators, output stages and high fidelity amplifiers.



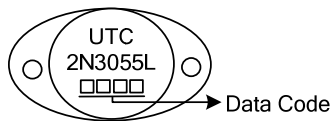
ORDERING INFORMATION

Ordering Number	Package	Pin Assignment			Packing
		1	2	3	
2N3055L-T30-Y	TO-3	B	E	C	Tray

Note: Pin Assignment: E: Emitter B: Base C: Case

<p>2N3055L-T30-Y</p> <p>(1) Packing Type</p> <p>(2) Package Type</p> <p>(3) Green Package</p>	<p>(1) Y: Tray</p> <p>(2) T30: TO-3</p> <p>(3) L: Lead Free</p>
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MARKING



■ ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ\text{C}$,unless otherwise specified)

PARAMETERS	SYMBOL	VALUE	UNITS
Collector-Base Voltage	V_{CBO}	100	V
Collector-Emitter Voltage	V_{CEO}	60	V
Emitter-Base Voltage	V_{EBO}	7	V
Collector-Emitter Voltage	V_{CEV}	70	V
Collector Current	I_C	15	A
Collector Peak Current(1)	I_{CM}	15	A
Base Current	I_B	7	A
Base Peak Current(1)	I_{BM}	15	A
Total Dissipation at $T_A=25^\circ\text{C}$	P_D	115	W
Max. Operating Junction Temperature	T_J	200	$^\circ\text{C}$
Storage Temperature	T_{STG}	-65 to 200	$^\circ\text{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Collector-Emitter Sustaining Voltage	$V_{CEO(sus)}$	$I_C=200\text{mA}$, $I_B=0\text{V}$	60			V
Collector-Emitter Sustaining Voltage	$V_{CER(sus)}$	$I_C=0.2\text{A}$, $R_{BE}=100\text{ Ohms}$	70			V
Collector Cut-off Current	I_{CEO}	$V_{CE}=30\text{V}$, $I_B=0$			0.7	mA
Collector Cut-off Current ($T_A=150^\circ\text{C}$)	I_{CEX}	$V_{CE}=100\text{V}$, $V_{BE(off)}=1.5\text{V}$			1.0	mA
		$V_{CE}=100\text{V}$, $V_{BE(off)}=1.5\text{V}$			5.0	mA
Emitter Cut-off Current	I_{EBO}	$V_{BE}=7\text{V}$, $I_C=0$			5.0	mA
ON CHARACTERISTICS						
DC Current Gain(note)	h_{FE}	$I_C=4\text{A}$, $V_{CE}=4\text{V}$	20		70	
		$I_C=10\text{A}$, $V_{CE}=4\text{V}$	5			
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=4\text{A}$, $I_B=400\text{mA}$			1.1	V
		$I_C=10\text{A}$, $I_B=3.3\text{A}$			3.0	V
Base-Emitter On Voltage	$V_{BE(on)}$	$I_C=4\text{A}$, $V_{CE}=4\text{V}$			1.5	V
SECOND BREAKDOWN						
Second Breakdown Collector with Base Forward Biased	$I_{s/b}$	$V_{CE}=60\text{V}$, $T=1.0\text{s}$, Non-repetitive	2.87			A
DYNAMIC CHARACTERISTICS						
Current Gain-Bandwidth Product	f_T	$I_C=0.5\text{A}$, $V_{CE}=10\text{V}$, $f=1\text{MHz}$	2.5			MHz
Small-Signal Current Gain	h_{FE}	$I_C=1\text{A}$, $V_{CE}=4\text{V}$, $f=1\text{kHz}$	15		120	
Small-Signal Current Gain Cut-off Frequency	f_{HFE}	$I_C=1\text{A}$, $V_{CE}=4\text{V}$, $f=1.0\text{kHz}$	10			kHz

Note: Pulse Test: Puls Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

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